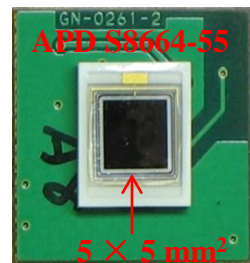
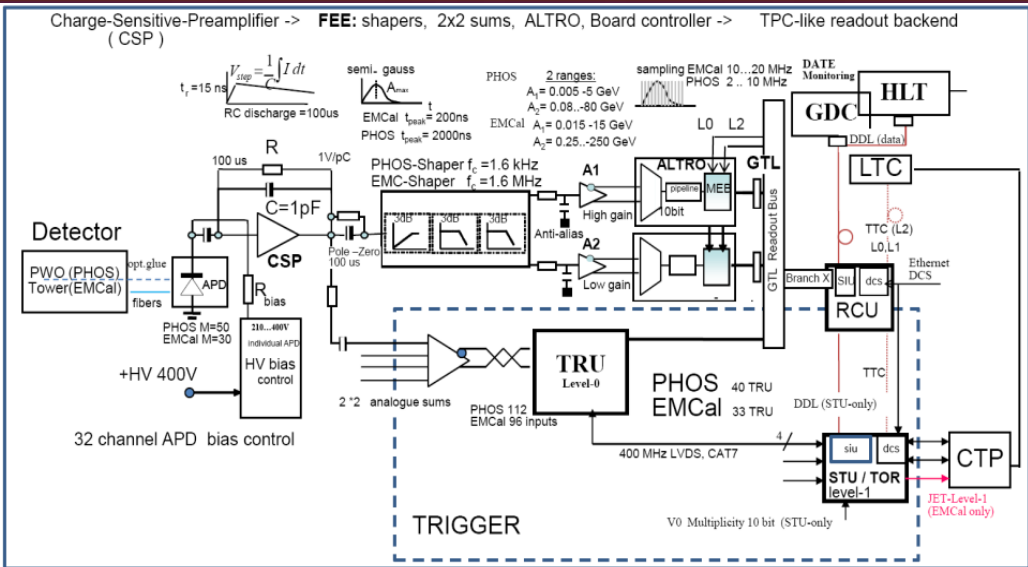
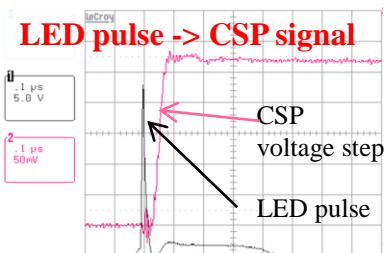
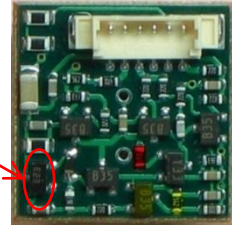


# Front-end Electronics overview

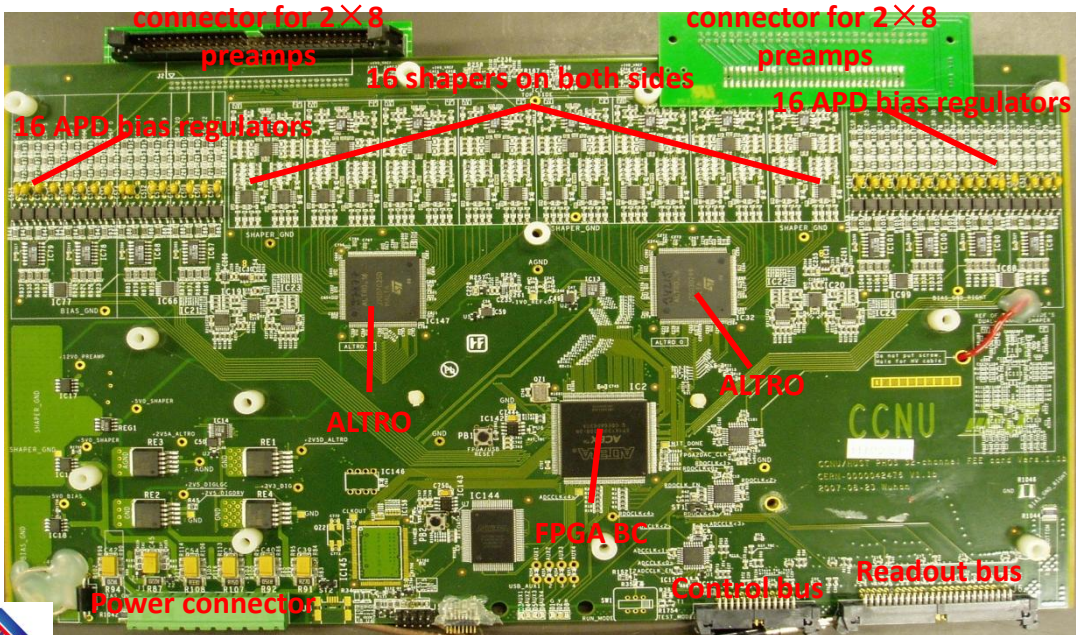
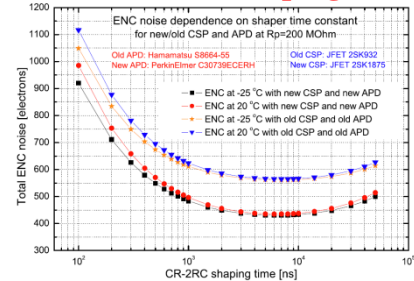


## Charge Sensitive Pre-amplifier (CSP)

JFET  
2SK932



## ENC noise Vs. shaping time

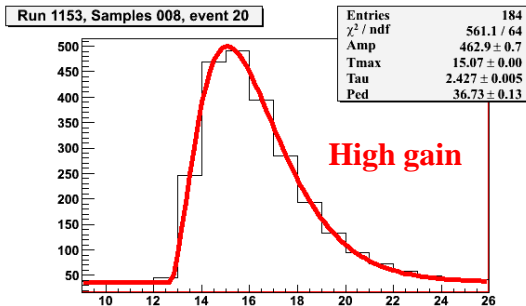
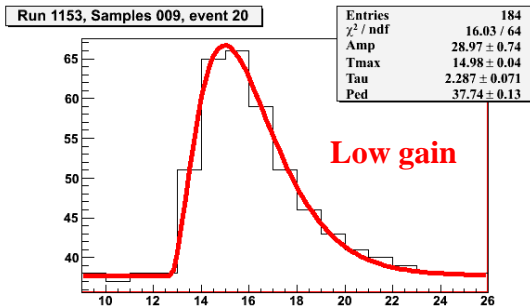


## FEE cards hardware properties:

- 32 ch. dual gain shapers, 64 readout channels
- RMS noise: ~ 3.2 MeV
- 14 bit dyn. energy range
- 32 HV regulators, 10 bit for APD bias
- Fast OR (2 x 2 crystals) for trigger
- 10 bit ADCs (ALTRO) 10 MHz
- Board controller firmware in FPGA
- GTL readout and control bus
- DAQ readout and DCS via RCU
- 5.5 watt, 349 x 210 mm<sup>2</sup>

# FEE readout characteristics

## High/Low gain shaper readout



## 2<sup>nd</sup> order Gamma2 fit:

$$V_{out}(t) = \left[ \frac{4Q \cdot A^2}{C_f} \right] \cdot \left[ \frac{t-t_0}{\tau} \right]^2 \cdot e^{-\frac{t-t_0}{\tau}}$$

Q = input charge on APD  
 $C_f = 1 \text{ pF}$   
 $\tau = 1000 \text{ ns (PHOS) or } 100 \text{ ns (EMCal)}$   
 A = CSP gain

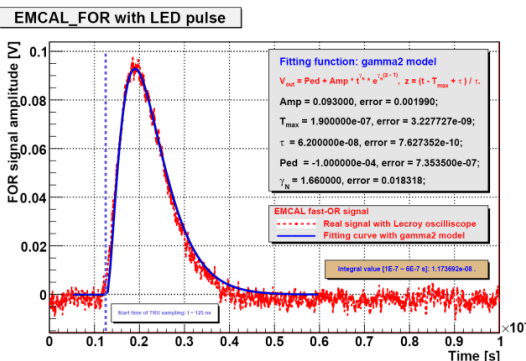
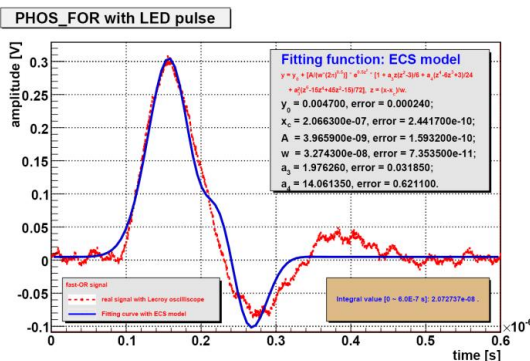
PHOS: energy ranges 0.005 GeV~5 GeV / 0.08 GeV~80 GeV for APD gain M=50

EMCal: energy ranges 0.015 GeV~15 GeV / 0.25 GeV~250 GeV for APD gain M=30

MIP ~ 215 MeV at room temperature at noise level of 30 MeV for PHOS.

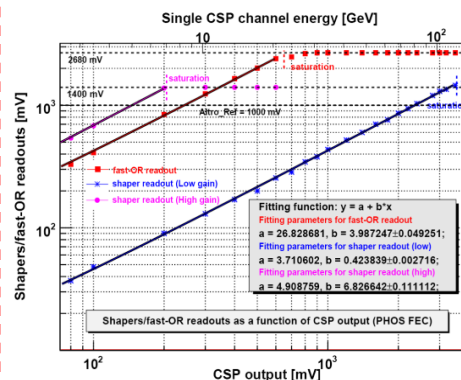
Signal to Noise Ratio at room temperature ~ 7

## fast OR differential signal for TRU



fast OR: analogue 2x2 CSP signal of  $\tau=100 \text{ ns}$

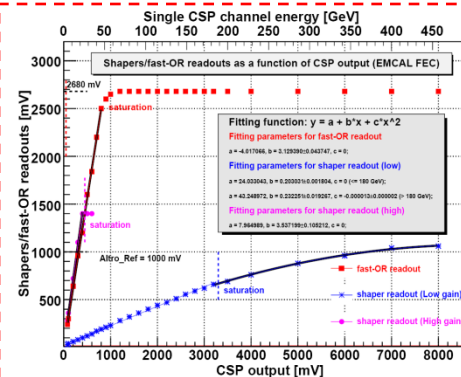
## Shapers/fast-OR readout linearity



- Linear range:**
  - fast OR saturation @ 2.5V:
  - LG value ~ 260mV
  - CSP value = 0.609 V
  - Saturation Energy ~ 21 GeV
- Non linear range:**
  - fast OR @ 2.68V
  - LG value ~ 380 mV
  - CSP value = 0.890 V
  - Saturation Energy ~ 30 GeV

- fast OR saturation at 2.5 - 2.74V differential
- fast OR / LG = ratio 9.403
- CSP gain = 29.2 uV/MeV (for M=50)
- LG shaper gain = 0.427
- HG shaper gain = 6.85

PHOS



- Linear range:**
  - fast OR saturation @ 2.5V:
  - LG value ~ 180 mV
  - CSP value = 0.792 V
  - Saturation Energy ~ 45 GeV
- Non linear range:**
  - fast OR @ 2.68V
  - LG value ~ 250 mV
  - CSP value = 1.091 V
  - Saturation Energy ~ 63 GeV

- fast OR saturation at 2.5 - 2.74V differential
- fast OR / LG = ratio 13.784
- CSP gain = 17.5 uV/MeV (for M=30)
- LG shaper gain = 0.229
- HG shaper gain = 3.66

EMCal